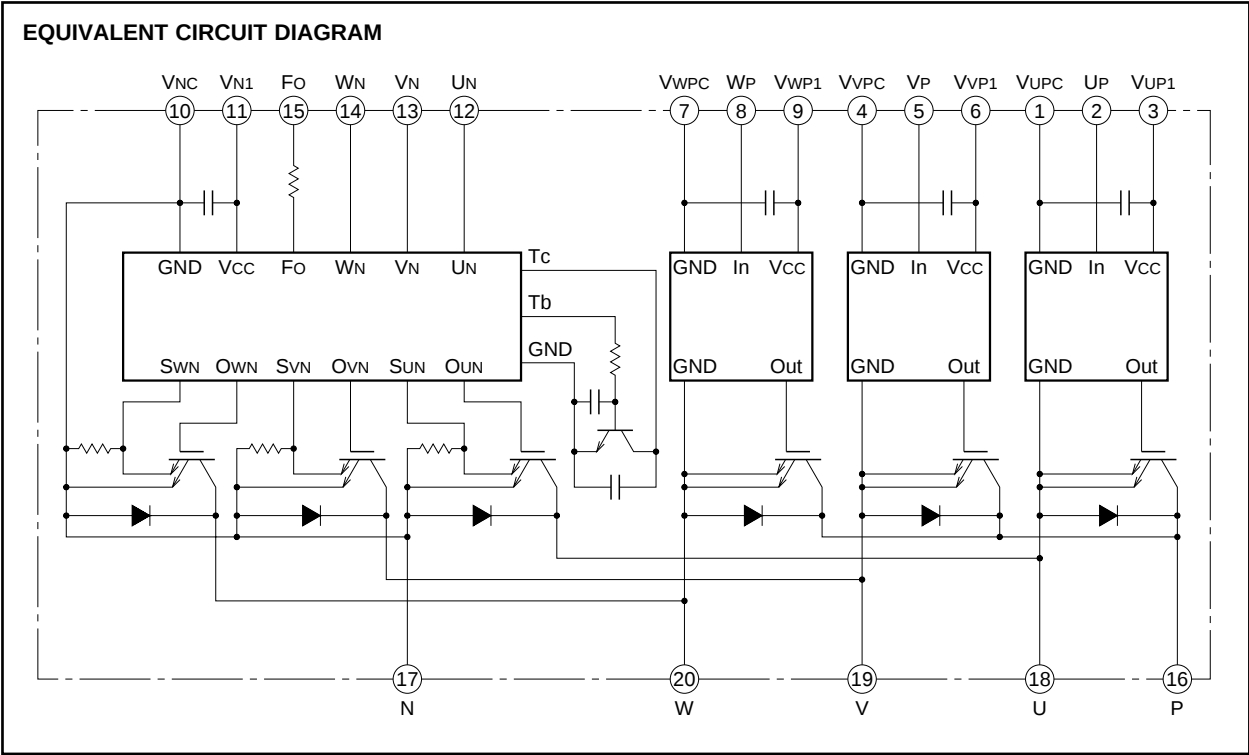


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FLAT-BASE TYPE
INSULATED PACKAGE



MAXIMUM RATINGS (T_j = 25°C, unless otherwise noted)

INVERTER PART

Symbol	Parameter	Conditions	Ratings	Unit
V _{CES}	Collector-emitter voltage	V _D = 15V, I _{CIN} = 10mA	600	V
±I _C	Collector current	T _c = 25°C	20	A
±I _{CP}	Collector current (peak)	T _c = 25°C	40	A
P _C	Collector dissipation	T _c = 25°C	56	W
T _j	Junction temperature		-20 ~ +125*	°C

* maximum instantaneous T_j ≤ 150°C

CONTROL PART

Symbol	Parameter	Conditions	Ratings	Unit
V _D	Supply voltage	Applied between : V _{UP1} -V _{UPC} , V _{VP1} -V _{VPC} V _{WP1} -V _{WPC} , V _{N1} -V _{NC}	20	V
I _{CIN}	Input current	Applied between : U _P -V _{UPC} , V _P -V _{VPC} , W _P -V _{WPC} , U _N · V _N · W _N -V _{NC}	20	mA
V _{FO}	Fault output supply voltage	Applied between : F _O -V _{NC}	20	V
I _{FO}	Fault output current	Sink current of F _O terminal	20	mA

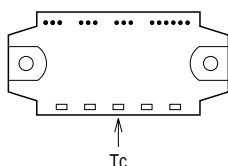
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TOTAL SYSTEM

Symbol	Parameter	Conditions	Ratings	Unit
V _{CC(Prot)}	Supply voltage protected by OC & SC	V _D = 13.5 ~ 16.5V, Inverter part, T _j = 125°C start	400	V
V _{CC}	Supply voltage	Applied between : P-N, operating time	450	V
V _{CC(surge)}	Supply voltage (surge)	Applied between : P-N, surge and non-operating time	500	V
T _C	Module case operating temperature	(Note 1)	-20 ~ +100	°C
T _{stg}	Storage temperature		-40 ~ +125	°C
V _{iso}	Isolation voltage	60Hz, sinusoidal, AC · 1 min	2500	V _{rms}

Note 1 : T_C measuring point is as shown below.

ELECTRICAL CHARACTERISTICS (T_j = 25°C, unless otherwise noted)

INVERTER PART

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
V _{CE(sat)}	Collector-emitter saturation voltage	V _D = 15V, I _{CIN} = 10mA	—	1.8	2.6	V
		I _C = 20A, T _j = 125°C		2.0	3.0	
V _{EC}	FWDi forward voltage	-I _C = 20A, V _D = 15V, I _{CIN} = 0mA	—	2.0	3.0	V
t _{on}	Switching time	V _D = 15V, I _{CIN} = 0mA ↔ 10mA V _{CC} = 300V, I _C = 20A T _j = 125°C (Per 1 arm) Inductive Load	0.5	2.5	3.5	μs
t _{rr}			—	0.1	—	μs
t _{c(on)}			—	0.2	0.8	μs
t _{off}			—	2.5	3.5	μs
t _{c(off)}			—	0.9	2.0	μs
I _{CES}	Collector-emitter cutoff current	V _{CE} = V _{CES} , I _{CIN} = 0mA	—	—	1	mA
		T _j = 125°C		—	10	

CONTROL PART

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
I _D	Circuit current	V _D = 15V, I _{CIN} = 0mA	—	25	35	mA
		V _{N1} -V _{N2} V _{XP1} -V _{XP2}		5	10	
I _{th(ON)}	Input on threshold current	Applied between : U _P -V _{UPC} , V _P -V _{VPC} , W _P -V _{WPC}	1	3	5	mA
I _{th(OFF)}	Input off threshold current	U _N · V _N · W _N -V _{N2}	1	3	5	mA
OC	Over current trip level	-20°C ≤ T _j ≤ 125°C, V _D = 15V (only N side)	28	34	—	A
SC	Short circuit trip level	-20°C ≤ T _j ≤ 125°C, V _D = 15V (only N side)	—	51	—	A
t _{off(OC)}	Over current delay time	V _D = 15V	—	10	—	μs
OT	Over temperature protection	Base-plate	100	110	120	°C
OT _r		Temperature detection, V _D = 15V				
UV	Supply circuit under voltage protection	-20°C ≤ T _j ≤ 125°C (only N side)	11.5	12.0	12.5	V
UV _r						
I _{FO(H)}	Fault output current (Note 2)	V _D = 15V, V _{FO} = 15V	—	—	0.01	mA
I _{FO(L)}			—	10	15	
t _{FO}	Minimum fault output pulse width (Note 2)	V _D = 15V	1.0	1.8	—	ms

Note 2 : Fault output is given only when the internal OC, SC, OT & UV protection. (only N side)

Fault output of OC, SC protection given pulse.

Fault output of OT, UV protection given pulse while over level. (OT is only N side)

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THERMAL RESISTANCES

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Tye.	Max.	
R _{th(j-c)Q}	Junction to case thermal resistances	Inverter IGBT part, per 1/6 module	—	—	2.0	°C / W
R _{th(j-c)F}		Inverter FWDi part, per 1/6 module	—	—	4.5	°C / W
R _{th(c-f)}	Contact thermal resistance	Case to fin, thermal grease applied, per 1/6 module	—	—	0.4	°C / W

MECHANICAL RATINGS AND CHARACTERISTICS

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Tye.	Max.	
—	Mounting torque	Mounting screw : M4	0.98	1.18	1.47	N·m
—	Weight		10	12	15	kg·cm
—			—	60	—	g

RECOMMENDED CONDITIONS FOR USE

Symbol	Parameter	Test conditions	Ratings	Unit
V _{CC}	Supply voltage	Applied between : P-N	≤ 400	V
V _D		Applied between : V _{UP1} -V _{UPC} , V _{VP1} -V _{VPC} V _{WP1} -V _{WPC} , V _{UN1} -V _{UNC} (Note 3)	15 ± 1.5	V
I _{CIN(ON)}	Input on current	Applied between : U _P , V _P , W _P , U _N , V _N , W _N	≥ 5	mA
I _{CIN(OFF)}	Input off current		≤ 1	mA
f _{PWM}	PWM input frequency	Using application circuit Opto-coupler's input signal	≤ 8	kHz
t _{dead}	Arm shoot-through blocking time	Using application circuit Opto-coupler's input signal	≥ 3	μs

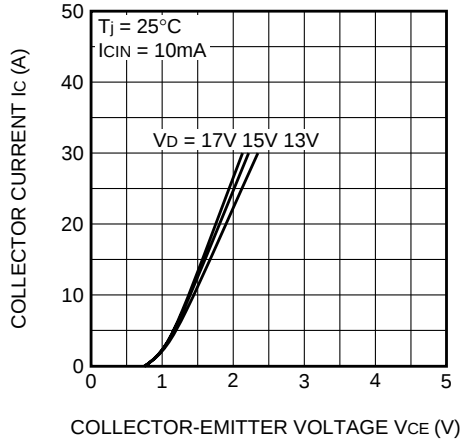
Note 3 : Permissible ripple value : dv/dt ≤ ±5V/μs, V_{ripple} ≤ 2V_{P-P}

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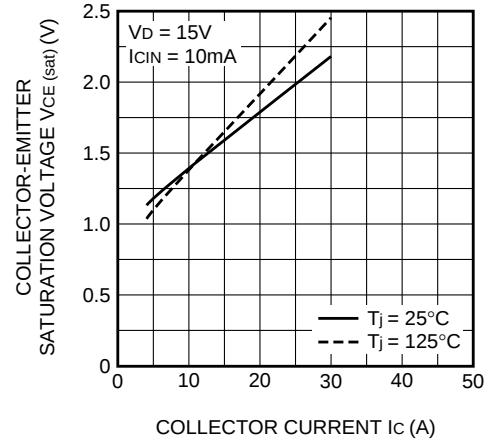
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PERFORMANCE CURVES

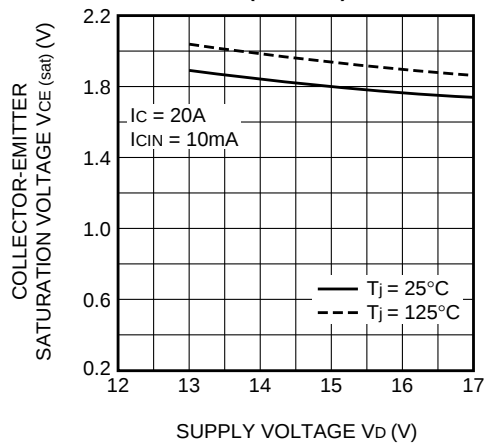
OUTPUT CHARACTERISTICS
(TYPICAL)



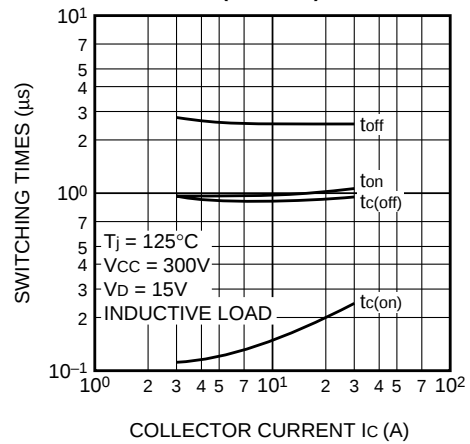
COLLECTOR-EMITTER SATURATION
VOLTAGE CHARACTERISTICS
(TYPICAL)



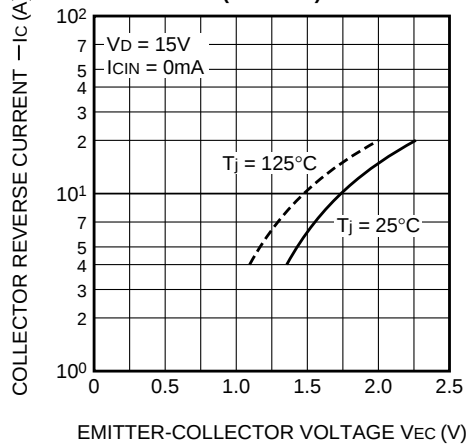
COLLECTOR-EMITTER SATURATION
VOLTAGE VS. SUPPLY VOLTAGE
(TYPICAL)



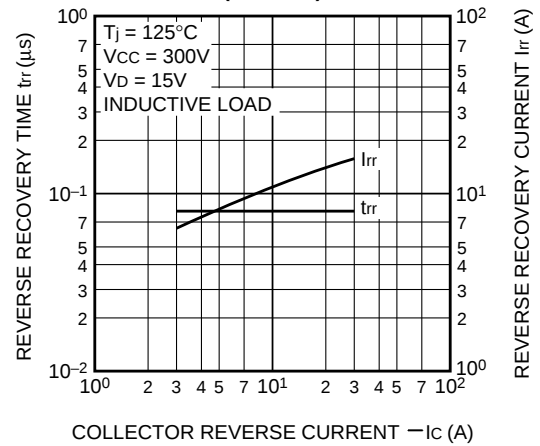
SWITCHING TIME VS.
COLLECTOR CURRENT
(TYPICAL)



FREE-WHEEL DIODE FORWARD
CHARACTERISTICS
(TYPICAL)



REVERSE RECOVERY CHARACTERISTICS
OF FREE-WHEEL DIODE
(TYPICAL)



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FLAT-BASE TYPE
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